MODELLING OF ENFETS FOR THE CREATININE DETECTION

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To cite this version:

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Abstract

Creatinine enzymatic field effect transistors (C-EnFETs) realised from a pH-sensitive field effect transistor (pH-ISFET) have been modelled by taking into account the enzymatic reaction, the diffusion phenomena of the main chemical species in the electrolyte, the related acid/basic chemical reactions in watery solution and the detection properties of the pH-ISFET sensitive gate. Thus, the concentrations of the main chemical species have been characterized near the sensitive gate, and the C-EnFET micro sensor detection properties have been studied according to the most influential parameters. A good fit has been shown between modelling and experimental results. The model has been developed for the optimization of creatinine-EnFETs in the field of haemodialysis, but is also fully compatible for other EnFETs based on pH-ISFET-metry.

Keywords: Modelling, EnFETs, creatinine detection
1. Introduction

Since its development in the sixties for patients suffering from chronic end-stage kidney failure, haemodialysis has been in constant evolution in order to improve health's care and life expectancy. Today, in order to proceed on its way, the dialysis efficiency must be known precisely by monitoring urea and creatinine concentration during haemodialysis treatment.

This goal will be achieved by developing integrated, disposable, low cost and reliable biochemical sensors fully adapted to medical analysis. These requirements can be reached using chemical field effect transistor (ChemFET) micro sensors [1]. Indeed, enzymatic layers have been thoroughly studied for the development of pH-ISFET-metry, i.e. for the adaptation of pH-sensitive ion sensitive field effect transistor (pH-ISFET) to biochemical detection. By using enzymes responsible for acid or basic chemical production, enzymatic field effect transistor (EnFET) based micro sensors have been realized for many applications including urea and creatinine detection [2-7]. However, in order to optimize the EnFETs micro sensors for an industrial haemodialysis application in terms of cost, their detection phenomena and properties must be modelled and understood.

Thus, this paper deals with the modelling of a creatinine-sensitive EnFET (C-EnFET) micro sensor using poly vinyl alcohol (PVA) based enzymatic layers.

2. Modelling

Creatinine EnFET detection principle is based on the use of a SiO$_2$/Si$_3$N$_4$ pH-ISFET adapted to enzymatic detection thanks to a PVA creatinine deiminase rich, enzymatic layer [7]. The Si$_3$N$_4$/PVA/electrolyte (water) sensitive structure has been described according to figure 1. The C-EnFET detection properties that were modelled are the enzymatic reaction, the diffusion phenomena of the main chemical species, i.e. creatinine C$_4$H$_7$N$_3$O and ammonia NH$_3$,
in the electrolyte, the \( \text{NH}_4^+ / \text{NH}_3 \) related acid/basic reactions into aqueous solution, and finally the pH-detection properties of the silicon nitride \( \text{Si}_3\text{N}_4 \) ISFET gate.

A. Modelling of the creatinine deiminase enzymatic reaction

The creatinine deiminase (CD-ase) enzymatic reaction is responsible for the creatinine hydrolysis into aqueous solution (equation 1):

\[
\text{creatinine} + \text{H}_2\text{O} \rightarrow \text{N-methyl hydantoïn} + \text{NH}_3
\]  

(1)

This enzymatic reaction has been modelled using the Michaelis – Menten equation:

\[
a = a_M \frac{[S]}{[S] + K_M}
\]

(2)

where \( a \) is the enzyme activity, \( a_M \) is the maximal activity (\( a_M = 16.67 \times 10^{-9} \) mol/s for 1 CD-ase unit), \([S]\) is the creatinine concentration in solution and \( K_M \) is the creatinine deiminase Michaelis constant.

In the following, since creatinine and N-methyl hydantoïn are not known to have any acid/basic properties, their consumption/production have been assumed to have no influence on the C-EnFET detection properties. Furthermore, no enzyme activity dependence with pH has been taken into account.

B. Modelling of the diffusion phenomena of creatinine and ammonia in the electrolyte
Diffusion phenomena of the most influential chemical species, i.e. creatinine $\text{C}_4\text{H}_7\text{N}_3\text{O}$ (named S for "substrate") and ammonia $\text{NH}_3$, into water have been modelled using the Fick law:

\[
\begin{align*}
\frac{\partial [S](x,t)}{\partial t} &= D_S \frac{\partial^2 [S](x,t)}{\partial x^2} - g(x,t) \\
\frac{\partial [\text{NH}_3]_p(x,t)}{\partial t} &= D_{\text{NH}_3} \frac{\partial^2 [\text{NH}_3]_p(x,t)}{\partial x^2} + g(x,t)
\end{align*}
\]

(3)

where $[S](x,t)$ is the creatinine concentration, $[\text{NH}_3]_p(x,t)$ is the ammonia global concentration produced, $D_S$ and $D_{\text{NH}_3}$ are the diffusion coefficients of creatinine and ammonia molecules into water respectively.

Since the PVA enzymatic layer is composed of at least 93% of water [8], the $D_S$ and $D_{\text{NH}_3}$ values have been assumed constant for all layer thicknesses (parameter $x$ in figure 1). Their values ($D_S = 1.35 \times 10^{-5}$ cm$^2$/s and $D_{\text{NH}_3} = 2.54 \times 10^{-5}$ cm$^2$/s) have been estimated according to the Einstein equation:

\[
D = A \frac{kT}{3M}
\]

(4)

where $A$ is a parameter related to the electrolyte, $k$ is the Boltzman constant, $T$ is the absolute temperature and $M$ is the molar mass of the studied molecule.

The $g(x,t)$ parameter represents the enzymatic consumption/production phenomena per time unit. Since the creatinine deiminase enzymatic reaction occurs only in the PVA layer, $g(x,t)$ has been chosen equal to zero in the electrolyte (figure 1). Thus, according to equation (1), $g(x,t)$ is given by:
where \( e_{PVA} \) is the PVA thickness and \( n_{enz} \) is the number of enzymatic units per volume unit in the PVA layer.

Thus, by resolving the system formed by equations (3) and (5), the \([S](x,t)\) and \([NH_3]_p(x,t)\) concentrations can be determined.

C. Modelling of the acid/basic chemical reaction in the electrolyte

The production of ammonia \( NH_3 \) in aqueous solution is known to be responsible for a pH variation according to the acid/basic relation:

\[
NH_3 + H_2O \rightleftharpoons NH_4^+ + OH^- \quad (6)
\]

Thus, the pH value, i.e. the \([H^+]\) ion concentration, can be calculated by studying the standard chemical reactions related to the \( NH_4^+/NH_3 \) acid/base couple (equations 7):

\[
\begin{align*}
\frac{[NH_4^+] + [NH_3]}{[NH_3]} &= [NH_3]_p \\
K_a &= \frac{[NH_3][H_2O^+]}{[NH_4^-]} \\
K_e &= [OH^-][H_3O^+] \\
[NH_4^+] + [H_3O^+] &= [OH^-] + C_t
\end{align*}
\quad (7)
\]

where \( K_a \) and \( K_e \) are respectively the \( NH_4^+/NH_3 \) acidity constant and the water ionic product (\( K_a = 5.62 \times 10^{-10} \) mol/l and \( K_e = 10^{-14} \) (mol/l)^2).
C\textsubscript{t} is a constant term describing the acid/basic properties of the initial solution. For a standard initial solution with a given pH\textsubscript{0} value, C\textsubscript{t} is given by:

\[ C_t = 10^{pH_0} - 10^{(pK_a - pH_0)} \]  

(8)

Assuming that time constants of the different acid/basic reactions (equations 7) are very low compared to those of the diffusion phenomena (equations 3), the \([H_3O^+]\)(x,t) concentration, i.e. the pH(x,t) function, can be related to the ammonia global concentration produces by the enzymatic reaction \([NH_3]_p\)(x,t) according to equations 9:

\[
\begin{align*}
\left[ \frac{[H_3O^+]\text{(x,t)}[NH_3]_p\text{(x,t)}}{[H_3O^+]\text{(x,t)} + K_a} \right] + [H_3O^+]\text{(x,t)} - \frac{K_e}{[H_3O^+]\text{(x,t)}} = C_t = 0 \\
pH\text{(x,t)} = -\log[H_3O^+]\text{(x,t)}
\end{align*}
\]  

(9)

D. Modelling of the pH-ISFET response

Finally, the C-EnFET threshold voltage \(V_T\) is related to the pH at the silicon nitride Si\textsubscript{3}N\textsubscript{4} surface according to the simplified site-binding model [9,10]:

\[ V_T = V_{T0} + s_0[pH(0,+\infty) - pH_{pzc}] \]  

(10)

where \(V_{T0}\) is the threshold voltage of the corresponding field effect transistor, \(s_0\) is the pH-ISFET sensitivity (given theoretically by the Nernst law or estimated experimentally), pH(0,+\infty) is the pH at the silicon nitride gate surface when the diffusion phenomena "steady state" is reached, and pH\textsubscript{pzc} is the point of zero charge (pH\textsubscript{pzc} has been estimated around 4 for Si\textsubscript{3}N\textsubscript{4} [10,11]).
In the following, since the $V_{TO}$ value is only related to the pH-ISFET technological fabrication [12], it is of no influence concerning the C-EnFET detection properties and it will not be taken into account, i.e. it will be chosen equal to zero.

3. Results and discussion

A. Study of the main chemical species concentrations

Figures 2 and 3 represent typical variations of the creatinine and ammonia concentrations $[S](x,t)$ and $[\text{NH}_3](x,t)$ near the sensor surface. They clearly show the creatinine consumption as well as the ammonia production. However, the main influence of the enzymatic reaction is given by the pH variations $pH(x,t)$ in proximity to the pH-ISFET sensitive surface (figure 4). It appears that the pH local increase reaches millimetric distances from the sensor surface and that a "steady state" is evidenced at the sensor pH-sensitive surface after around 10 seconds (figure 5). Thus, due to the maximal limit $pH(0,+\infty)$, the C-EnFET detection properties can be thoroughly studied (equation 10).

B. Study of the most influential parameters

Firstly, the influence of the PVA thickness $e_{PVA}$ has been studied. For $e_{PVA}$ values ranging between 1 and 10 microns [8], no variation of the sensor detection properties has been found. Indeed, in all cases, the PVA thickness is insignificant compared to the typical lengths of the pH increase (figure 4). Therefore, the enzymatic reaction can be considered as a surface phenomenon occurring at the sensor sensitive gate. In the following, the PVA thickness has been fixed according to profilometric experimental measurements [8].

According to theoretical equations, the most influential parameters are the number of creatinine deiminase enzymatic units per volume unit in the PVA layer $n_{enz}$, the creatinine
deiminase Michaelis constant $K_M$, and the solution initial pH value $pH_0$. Their influences on the C-EnFET sensor detection properties have been studied on ranges appropriate with creatinine detection in the field of haemodialysis (main values are given in bold characters):

- [creatinine] (mol/L): [10^{-7} - 10^{-2}]
- $K_M$ (mol/L): [10^{-4} - 10^{0}] (3.5 10^{-3})
- $n_{enz}$ (unit/cm$^3$): [10^{1} - 10^{6}] (10^4)
- $pH_0$: [6 - 8] (7.5)

Figure 6 represents typical C-EnFET responses with creatinine deiminase Michaelis constant $K_M$. For the lowest values, saturation of the creatinine detection properties is evidenced. These saturation phenomena should be related with the creatinine diffusion from the electrolyte towards the PVA enzymatic layer. They also allow to define the C-EnFET detection limit around 10^{-7} mol/L. Finally, figure 6 shows that the $K_M$ increase is responsible for the shift of the C-EnFET detection range towards the higher creatinine concentration.

In the same way, figure 7 represents typical C-EnFET responses with creatinine deiminase enzymatic units per volume unit in the PVA layer $n_{enz}$. As $n_{enz}$ is decreased towards the lower extreme, creatinine detection properties are lost. Conversely, as $n_{enz}$ is increased towards the highest extreme, the saturation phenomena of creatinine detection are highlighted. These responses were predicted by equation (5).

Finally, since the studied enzymatic detection principle is based on pH-metry, it depends on the solution initial pH value $pH_0$ (equation 8). In fact, it appears that the $pH_0$ parameter influences the C-EnFET detection properties only for the lowest creatinine concentrations (figure 8). For the haemodialysis application, this is no drawback since the $pH_0$ value for human dialysate is known to be constant around 7.4.
Taking into account the whole enzymatic reaction, it appears that the $K_M$ and $n_{enz}$ parameters allow the definition of C-EnFET detection range and sensitivity. For instance, for a creatinine deiminase provided by Sigma (from micro-organism EC 3.5.4.21, $K_M \approx 3.5 \times 10^{-3}$ mol/L) and tested for the realisation of creatinine EnFETs [7], figure 7 define clearly the optimal $n_{enz}$ value in term of cost, while maintaining quasi-linear response and the highest sensitivity ($\approx 45 \text{ mV/pCreatinine}$) for the concentration range appropriate to haemodialysis ($10^{-5} - 10^{-3}$ mol/L). In this case, the optimal value is for $n_{enz} \approx 10^4$ unit/cm$^3$.

C. Comparison between modelling and experience

In order to validate the creatinine sensor model, it was compared to experimental results from related literature. In fact, in order to take into account the threshold voltage non-reproducibility from one EnFET to another (for technological reasons), its variations $\delta V$ has been studied as a function of the creatinine concentration, taking the lowest value ($\approx 2 \times 10^{-5}$ mol/L) as reference (figure 9).

In previous works [7], different sensor responses had been obtained by using a creatinine deiminase provided by Sigma. According to our experimental procedures, the main detection parameters can be resumed as following:

- $K_M \approx 3.5 \times 10^{-3}$ mol/L
- $n_{enz} \approx 2 \times 10^3$ unit/cm$^3$
- $pH_0 \approx 7.5$
- $s_0 \approx 50 \text{ mV/pH}$
Since $K_M$, $pH_0$ and $s_0$ values are directly related to the enzyme, the initial solution and the pH-ISFET characteristics respectively, experimental and modelling results have been fitted thanks to the $n_{enz}$ parameter, in good agreement with the experimental value (figure 9):

- #1: $n_{enz} \approx 2 \times 10^3 \text{ unit/cm}^3$
- #2: $n_{enz} \approx 10^3 \text{ unit/cm}^3$

Thus, according to the model, the experimental measurement discrepancy evidenced in [7] has to be related to the $n_{enz}$ parameter and therefore to the creatinine deactivation with processing and/or storage conditions [8].

All in all, a good fit has been obtained with experimental results, validating the whole model of the Creatinine-EnFET micro sensor.

4. Conclusion

The creatinine EnFET detection principle based on pH-ISFET-metry has been modelled by taking into account the enzymatic reaction, the diffusion phenomena of the main chemical species in the electrolyte, the related acid/basic chemical reactions into aqueous solution, and finally the detection properties on the pH-ISFET sensitive gate. Thus, it has been possible to characterize the concentration variations of the main interfering chemical species near the sensor surface, and to define the most influential parameters on the C-EnFET micro sensor detection properties. The model has been compared with experimental results and a good agreement has been evidenced for the concentration range appropriate to haemodialysis ($10^{-5} - 10^{-3} \text{ mol/L}$).

This modelling enables a real understanding of the EnFETs detection principle based on pH-ISFET-metry. It opens solution for improving the EnFETs sensor reliability, taking
especially into account biochemical aspects related to the enzyme processing, storage or ageing. It has first been developed for the detection of creatinine in the field of haemodialysis, but is fully compatible with other similar enzymatic detection. It will be soon applied to the urease enzyme and the optimization of urea-EnFETs still for haemodialysis applications.

References


Biographies

Pierre Temple-Boyer was born on October 25, 1966. He received his Master’s Degree in electronic engineering from the Ecole Supérieure d'Electricité (Paris – France) in 1990. He joined the Laboratoire d'Architecture et d'Analyse des Systèmes of the French Centre National de la Recherche Scientifique (LAAS-CNRS) in 1992 and received the PhD degree from the Institut National des Sciences Appliquées de Toulouse (France) in 1995. Since then, as a senior researcher, he has been working on the development of micro- and nanotechnologies.
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William Sant was born on May 18, 1969. He received his Master’s Degree in electronics in 1996 and his Diplome d’Etudes Approfondies in Microelectronics from the Université Paul Sabatier de Toulouse (France) in 1999. He joined the Laboratoire d’Architecture et d’Analyse des Systèmes of the French Centre National de la Recherche Scientifique (LAAS-CNRS) in 2000 and received the PhD degree from the Université Paul Sabatier de Toulouse (France) in 2004. Since then, he has been working on the development of ChemFETs micro sensors for medical applications.
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FIGURE CAPTIONS

Figure 1: description of the Si$_3$N$_4$/PVA/electrolyte structure

Figure 2: creatinine concentration $[S](x,t)$

Figure 3: ammonia concentration $[\text{NH}_3](x,t)$

Figure 4: $pH(x,t)$ function

Figure 5: $pH$ temporal variations at the $pH$-ISFET sensitive surface

Figure 6: creatinine EnFET responses with CD-ase Michaelis constant $K_M$

Figure 7: creatinine EnFET responses with number of enzymatic units per volume unit $n_{enz}$

Figure 8: creatinine EnFET responses with solution initial $pH$ value $pH_0$

Figure 9: Creatinine-EnFET responses: comparison between modelling and experience
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